NSN 5962-01-360-4070

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View Online at https://aeroba

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Body Length:
Between 1.635 inches and 1.680 inches
Body Width:
Between 0.565 inches and 0.605 inches
Body Height:
Between 0.160 inches and 0.220 inches
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Ac/rmpe react basic
Features Provided:
Electrostatic sensitive
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Criticality Code Justification:
Cbbl
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, epro (27c10)
Voltage Rating And Type Per Characteristic:
-0.6 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
170.00 nanoseconds access
Memory Device Type:
Programmed
Memory Capacity:
128kx8
Special Features:
Hcp; esd; ultraviolet eprom; altereditem from 11293/15-1326286-1 (5962-8961404xx) program using 11293/00-0035
Nuclear Hardness Critical Feature:
Hardened

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

32 beam lead

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Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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